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Sub-Ångstrom Electron Microscopy for Sub-Ångstrom Nano-Metrology

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The revolution in nanoscale science and technology requires instrumentation for observation and metrology – we must be able to see and measure what we build. Because nano-devices operate on the level of a few molecules, or even a few atoms, accurate atomic-scale imaging is called for. **High-resolution aberration-corrected electron microscopes (both TEM and STEM) can provide valuable measurements at the sub-Ångstrom level.**

In general, resolution is accepted as the ability to determine if an image feature represents two objects rather than one. Rayleigh's original resolution criterion, the accepted standard in optics, was derived as a yardstick for judging when two sources of light (stars) could be distinguished from a single source [1]. In the field of microscopy, resolution has continued to be based on the ability to determine if detail in an image represents distinct (separated) objects. In high-resolution electron microscopy these objects are atoms. A resolution of $|\mathbf{d}|$ is achieved when atoms separated by a (projected) distance $|\mathbf{d}|$ can be perceived as separate objects. Although demonstration of resolution $|\mathbf{d}|$ requires the presence of the corresponding spatial frequency $1/|\mathbf{d}|$ in the TEM image spectrum, the mere presence of the $1/|\mathbf{d}|$ frequency is not sufficient to validate a corresponding resolution of $|\mathbf{d}|$ [2]. Similarly, in a scanning transmission electron microscope (STEM), a probe size of $|\mathbf{d}|$ is a necessary, but not sufficient, requirement to achieve a resolution of $|\mathbf{d}|$.

Test samples with atoms separated by known amounts can be used to measure sub-Ångstrom resolutions. Specimens with diamond cubic and zinblende structures can be oriented to provide pairs of atoms in “dumbbell” configurations with well-characterized separations ranging from 1.6Å to 0.5Å. Figure 1 shows spacings available from some test specimens [3], together with images obtained at resolutions of 0.89Å and 0.78Å in the LBNL One-Ångstrom Microscope (OÅM), a modified HRTEM [4]. Similar images have been obtained using HR-STEMs [5, 6]. Many nanodevices use interfaces on [110] and [112] planes.

To properly characterize nanomaterials, it is important to be able to see all the atoms, even the light ones. Improved resolution has the advantage of narrowing the peaks corresponding to heavy atoms, thus allowing the lighter atom peaks to become visible. The OÅM has demonstrated that sub-Ångstrom resolution gives us the ability to image lithium, the lightest of all metal atoms. Figure 2 shows peaks corresponding to the positions of cobalt, oxygen and lithium atoms in the lithium battery material, LiCoO₂ [7].

Characterization of catalyst nanoparticles requires knowledge of the internal structures of the particles as well as their shapes. As well as revealing atom column positions, sub-Ångstrom phase-image microscopy can also provide a good estimate of the number of atoms making up each column in a single-atom-species particle [8]. Figure 3 shows a gold nanoparticle with each atom column visible as a white peak. The arrangement of the atom columns reveals the shape of the 70Å diameter particle, as well as the fact that it is multiply-twinned.

Over the next decade, extension of TEM and STEM resolutions to half-Ångstrom levels by next-generation aberration-corrected electron microscopes will advance the capabilities of these essential tools for atomic-scale structural characterization [9]. Because improvements in resolution allow for separation of atom columns in many more projection directions, these microscopes will provide much improved three-dimensional characterization of the shape and internal structure of nanodevices and catalyst nanoparticles (perhaps even true 3-D imaging), and hence provide essential feedback in the nano-theory/construction/measurement loop [10].

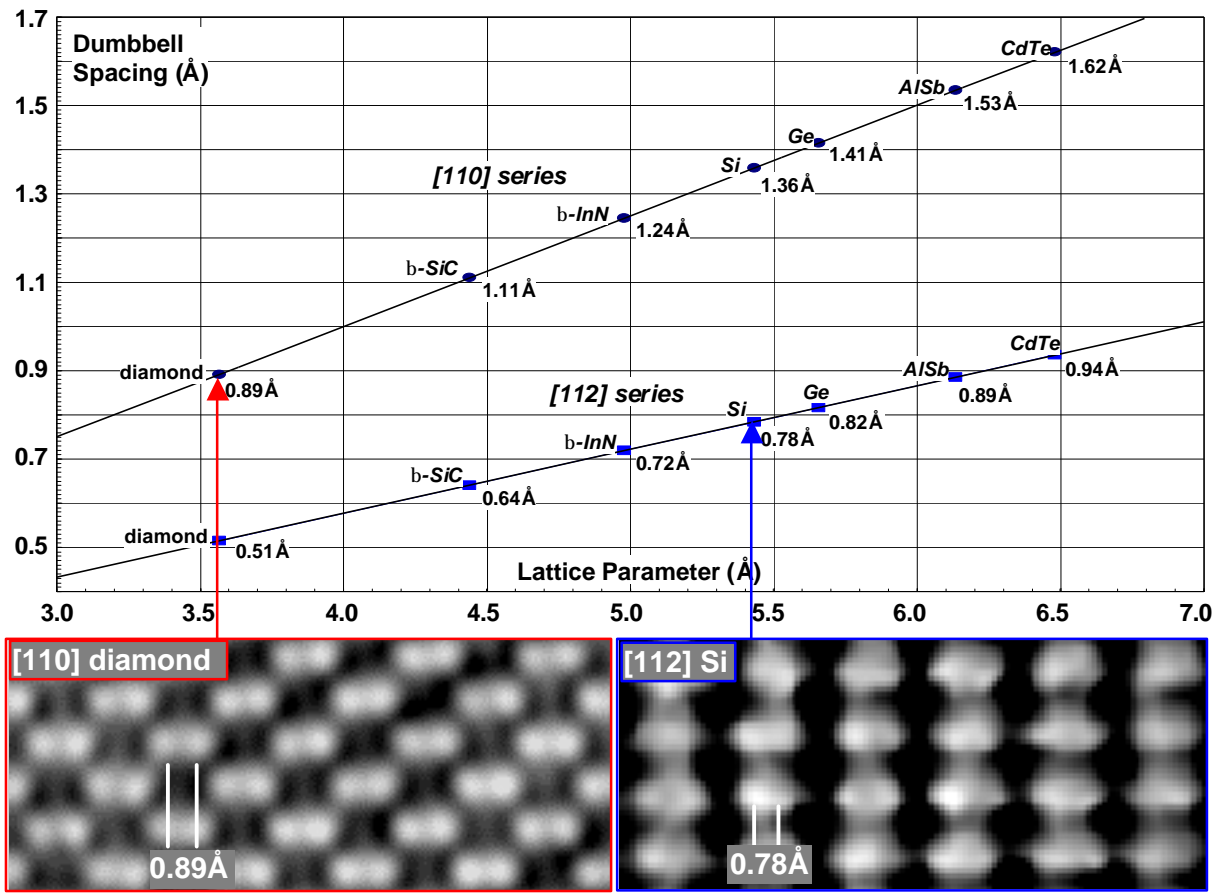
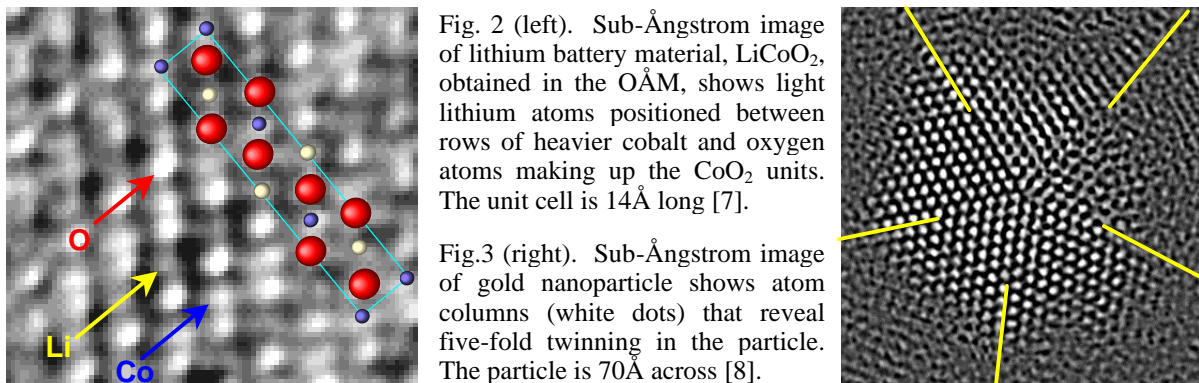


Fig. 1. Test specimens can provide separations of atom columns in atomic “dumbbells” ranging from 1.62 Å to 0.51 Å for samples in [110] and [112] orientations. Images obtained on the OAM [4] show the 0.89 Å carbon atom spacing in [110] diamond (left) and the 0.78 Å silicon atom spacing (barely) in [112] silicon (right).



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 [10] Supported by the Director, Office of Science, Office of Basic Energy Sciences, Materials Science Division, DOE (contract DE-AC03-76SF00098), and Asst. Sec. for EERE, Office of FreedomCAR and Vehicle Tech. for the HTML User Program, ORNL, managed by UT-Battelle, LLC for DOE (contract DE-AC05-00OR22725).